

SBL2030PT - SBL2060PT

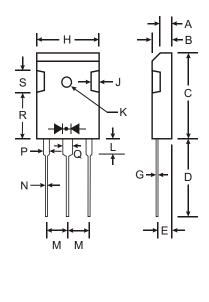
20A SCHOTTKY BARRIER RECTIFIER

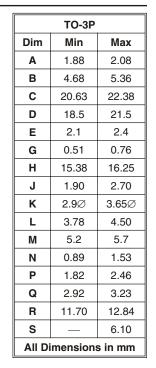
Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application

Mechanical Data

- Case: Molded Plastic
- Plastic Material UL Flammability Classification 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Body
- Marking: Type Number
- Weight: 5.6 grams (approx)





Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic | Symbol | SBL 2030PT | SBL 2035PT | SBL 2040PT | SBL 2045PT | SBL 2050PT | SBL 2060PT | Unit |
|---|--|---------------|---------------|---------------|---------------|---------------|---------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 30 | 35 | 40 | 45 | 50 | 60 | V |
| RMS Reverse Voltage | V _{R(RMS)} | 21 | 24.5 | 28 | 31.5 | 35 | 42 | V |
| Average Rectified Output Current (Note 1) @ T _C = 100°C | , lo | 20 | | | | | A | |
| Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | IFSM | 250 | | | | | А | |
| Forward Voltage Drop @ $I_F = 10A$, $T_C = 25^{\circ}$ | C V _{FM} | 0.55 0.75 | | | | 75 | V | |
| $\begin{array}{llllllllllllllllllllllllllllllllllll$ | | 1.0 50 | | | | | | mA |
| Typical Total Capacitance (Note 2) | CT | 1100 | | | | | | pF |
| Typical Thermal Resistance Junction to Case (Note 1) | Rejc | 2.5 | | | | | | °C/W |
| Operating and Storage Temperature Range | Tj, TSTG | -65 to +150 | | | | | | °C |

Notes: 1. Thermal resistance junction to case mounted on heatsink. 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

